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Contents

vii Conference Committee

SESSION 1	SPECIAL TOPICS I
8473 02	Laser processing of solar cells (Keynote Paper) [8473-1] D. E. Carlson, Carlson PV (United States)
8473 03	Understanding and enabling laser processing of solar materials through temporal pulse control (Invited Paper) [8473-2] M. Rekow, T. Panarello, ESI - PyroPhotonics Lasers Inc. (Canada); N. Falletto, M. Guevremont, EOLITE Systems (France)
8473 04	Modeling of contact geometry and dopant profile during laser-silicon interaction [8473-3] A. Raghavan, J. J. Blecher, T. A. Palmer, E. W. Reutzel, T. DebRoy, The Pennsylvania State Univ. (United States)
8473 06	Laser and thermal treatments for reclamation of silicon solar cells performance [8473-5] A. H. Al-Musawi, Univ. of Baghdad (Iraq)
SESSION 2	LASER DOPING AND CONTACTING I
8473 07	Laser-based foil rear side metallization for crystalline silicon solar cells (Keynote Paper) [8473-6] J. Nekarda, M. Graf, A. Rodofili, A. Wolf, R. Preu, Fraunhofer-Institut für Solare
	Energiesysteme (Germany)
8473 08	Influence of wavelength on laser doping and laser-fired contact processes for c-Si solar cells (Invited Paper) [8473-7]
	C. Molpeceres, M. I. Sánchez-Aniorte, M. Morales, D. Muñoz, Univ. Politécnica de Madrid (Spain); I. Martín, P. Ortega, M. Colina, C. Voz, R. Alcubilla, Univ. Politècnica de Catalunya (Spain)
8473 09	Laser doping for high-efficiency silicon solar cells [8473-8] U. Jäger, A. Wolf, B. Steinhauser, J. Benick, J. Nekarda, R. Preu, Fraunhofer-Institut für Solare Energiesysteme (Germany)
8473 0A	Laser doping from spin-on sources for selective emitter silicon solar cells [8473-9] A. Slaoui, P. Prathap, J. Bartringer, Institut d'Électronique du Solide et des Systèmes, CNRS (France)

SESSION 3	LASER ANNEALING AND CRYSTALLIZATION
8473 0C	Laser processing for thin film crystalline silicon solar cells [8473-11] A. Slaoui, A. Chowdhurya, P. Prathap, Z. Said-Bacar, Institut d'Électronique du Solide et des Systèmes, CNRS (France); A. Bahouka, F. Mermet, IREPA LASER (France)
8473 0D	Nanosecond laser annealing to decrease the damage of picosecond laser ablation of anti-reflection layers on textured silicon surfaces [8473-12] A. A. Brand, A. Knorz, R. Zeidler, JF. Nekarda, R. Preu, Fraunhofer-Institut für Solare Energiesysteme (Germany)
8473 OE	Laser nucleation and solid phase crystallization of a-Si:H [8473-13] M. S. Dabney, National Renewable Energy Lab. (United States) and Colorado School of Mines (United States); A. H. Mahan, M. F. A. M. van Hest, D. S. Ginley, National Renewable Energy Lab. (United States)
8473 OF	Pulsed and continuous wave solid phase laser annealing of electrodeposited CuInSe ₂ thin films [8473-14] A. Bhatia, The Univ. of Utah (United States); H. Meadows, A. Crossay, P. J. Dale, Univ. du Luxembourg (Luxembourg); M. A. Scarpulla, The Univ. of Utah (United States)
SESSION 4	LASER SCRIBING AND STRUCTURING I
8473 0G	Review of laser material interaction to improve CIGSeS thin film solar cells (Invited Paper) [8473-15] N. G. Dhere, A. Kaul, J. Shimada, Univ. of Central Florida (United States); A. Kar, CREOL, The College of Optics and Photonics, Univ. of Central Florida (United States)
8473 OH	Laser-assisted micro/nanoscale material processing and in-situ diagnostics for solar applications (Invited Paper) [8473-16] D. J. Hwang, Stony Brook Univ., State Univ. of New York (United States); C. P. Grigoropoulos, Univ. of California, Berkeley (United States)
SESSION 5	SPECIAL TOPICS II
8473 OM	Laser parameters for silicon solar cell processing: a simulation of heat transfer and material modification [8473-21] T. Baier, G. Glaeser, H. Wanka, Manz AG (Germany)
8473 ON	Extending the limits of laser beam shaping for PV-cell manufacturing [8473-22] I. Steiner, T. Mitra, LIMO Lissotschenko Mikrooptik GmbH (Germany)
8473 00	Applying field mapping refractive beam shapers in laser technologies for solar energy [8473-23] A. Laskin, V. Laskin, AdlOptica Optical Systems GmbH (Germany)

SESSION 6	LASER SCRIBING AND STRUCTURING II
8473 0Q	Novel approach to short-pulse and ultra-short pulse laser ablation of silicon nitride passivation layers [8473-25] M. Schulz-Ruhtenberg, D. Trusheim, M. Smeets, J. Holtkamp, A. Gillner, Fraunhofer-Institut für Lasertechnik (Germany)
8473 OR	Laser assisted patterning of hydrogenated amorphous silicon for interdigitated back contact silicon heterojunction solar cell [8473-26] S. De Vecchi, T. Desrues, F. Souche, D. Muñoz, Institut National de l'Energie Solaire (France); M. Lemiti, Institut National des Sciences Appliquées de Lyon, Univ. de Lyon (France)
8473 OS	Mechanisms of lifetime degradation in Si/ARC samples patterned by laser lift-off [8473-27] K. L. Saenger, IBM T.J. Watson Research Ctr. (United States)
8473 OT	Ytterbium-pulsed fiber laser percussion drilling silicon for emitter wrap through solar cells [8473-28] Y. Huang, X. Zhu, H. Zhu, Institute of Semiconductors (China)
SESSION 7	LASER DOPING AND CONTACTING II
8473 OW	Parameter optimization of laser-doped selective emitters for applications in silicon solar cells [8473-31] H. E. Heinrichs, E. W. Reutzel, S. Ashok, S. Mohney, The Pennsylvania State Univ. (United States)
8473 OX	Laser processes and system technology for the production of high-efficient crystalline solar cells [8473-32] R. Mayerhofer, R. Hendel, W. Zhu, S. Geiger, Rofin-Baasel Lasertechnik GmbH & Co. KG (Germany)
	Author Index

Proc. of SPIE Vol. 8473 847301-6

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Special Topics I

States)

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- Laser Doping and Contacting I
 Mool Gupta, University of Virginia (United States)
- Laser Annealing and Crystallization
 David J. Hwang, Stony Brook University (United States)
- Laser Scribing and Structuring I
 Corey M. Dunsky, Veeco Instruments Inc. (United States)
- 5 Special Topics II

Aravinda Kar, CREOL, The College of Optics and Photonics, University of Central Florida (United States)

6 Laser Scribing and Structuring II Edward W. Reutzel, Applied Research Laboratory, The Pennsylvania State University (United States) Laser Doping and Contacting II
 Jan Nekarda, Fraunhofer-Institut für Solare Energiesysteme (Germany)